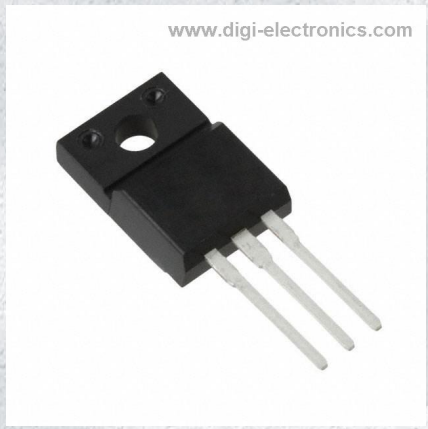
2SD12680P Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number	2SD12680P-DG
Manufacturer	Panasonic Electronic Components
Manufacturer Product Number	2SD12680P
Description	TRANS NPN 80V 3A TO220F-A1
Detailed Description	Bipolar (BJT) Transistor NPN 80 V 3 A 30MHz 2 W Through Hole TO-220F-A1

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
2SD12680P	Panasonic Electronic Components
Series:	Product Status:
-	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
NPN	3 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ Ib, Ic:
80 V	500mV @ 100mA, 2A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
10µA (ICBO)	130 @ 500mA, 2V
Power - Max:	Frequency - Transition:
2 W	30MHz
Operating Temperature:	Mounting Type:
150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-220-3 Full Pack	TO-220F-A1
Base Product Number:	
2SD126	

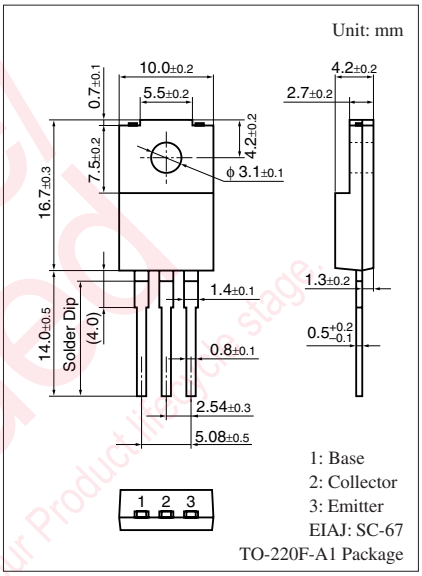
Environmental & Export classification

Moisture Sensitivity Level (MSL):	ECCN:
1 (Unlimited)	EAR99
HTSUS:	
8541.29.0075	

2SD1268

Silicon NPN epitaxial planar type

For power switching



■ Features

- Low collector-emitter saturation voltage $V_{CE(sat)}$
- Satisfactory linearity of forward current transfer ratio h_{FE}
- Large collector current I_C
- Full-pack package which can be installed to the heat sink with one screw.

■ Absolute Maximum Ratings $T_C = 25°C$

Parameter		Symbol	Rating	Unit
Collector-base voltage (Emitter open)		V_{CBO}	130	V
Collector-emitter voltage (Base open)		V_{CEO}	80	V
Emitter-base voltage (Collector open)		V_{EBO}	7	V
Collector current		I_C	3	A
Peak collector current		I_{CP}	6	A
Collector power dissipation	$T_a = 25°C$	P_C	30	W
			2.0	
Junction temperature		T_j	150	°C
Storage temperature		T_{stg}	−55 to +150	°C

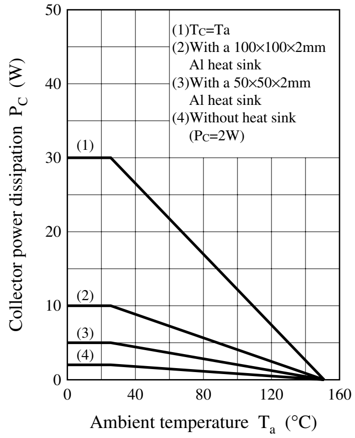
■ Electrical Characteristics $T_C = 25°C \pm 3°C$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-emitter voltage (Base open)	V_{CEO}	I_C = 10 mA, I_B = 0	80			V
Collector-base cut-off current (Emitter open)	I_{CBO}	V_{CB} = 100 V, I_E = 0			10	μA
Emitter-base cut-off current (Collector open)	I_{EBO}	V_{EB} = 5 V, I_C = 0			50	μA
Forward current transfer ratio	h_{FE1}	V_{CE} = 2 V, I_C = 0.1 A	45			—
	h_{FE2} *	V_{CE} = 2 V, I_C = 0.5 A	60		260	
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C = 2 A, I_B = 0.1 A			0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	I_C = 2 A, I_B = 0.1 A			1.5	V
Transition frequency	f_T	V_{CE} = 10 V, I_C = 0.5 A, f = 10 MHz		30		MHz
Turn-on time	t_{on}	I_C = 0.5 A, I_{B1} = 50 mA, I_{B2} = −50 mA		0.5		μs
Storage time	t_{stg}	V_{CC} = 50 V		2.5		μs
Fall time	t_f			0.15		μs

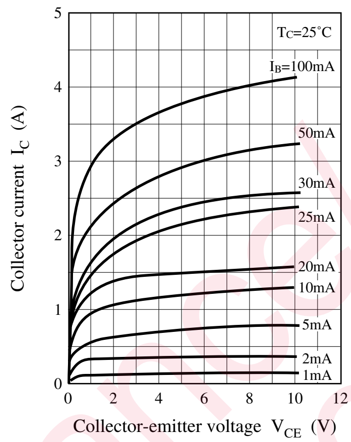
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.
2. *: Rank classification

Rank	R	Q	P
h_{FE2}	60 to 120	90 to 180	130 to 260

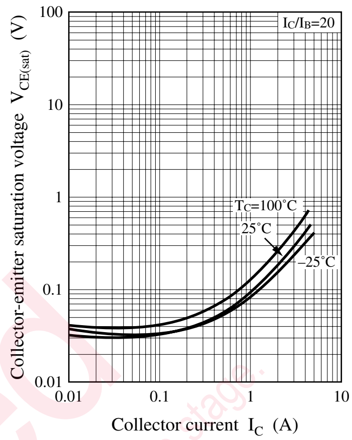
P_C — T_a



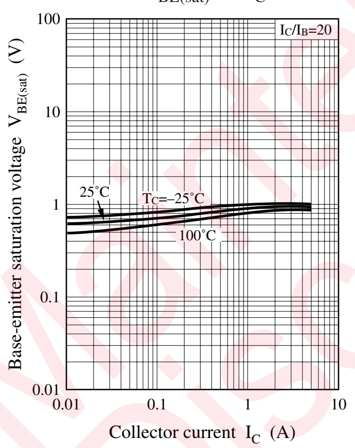
I_C — V_{CE}



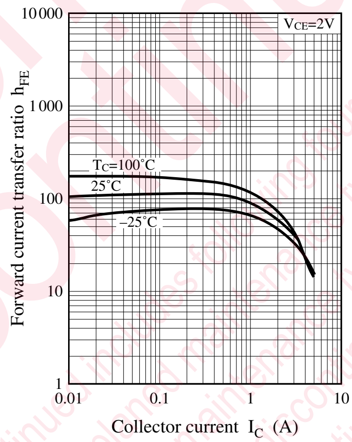
$V_{CE(sat)}$ — I_C



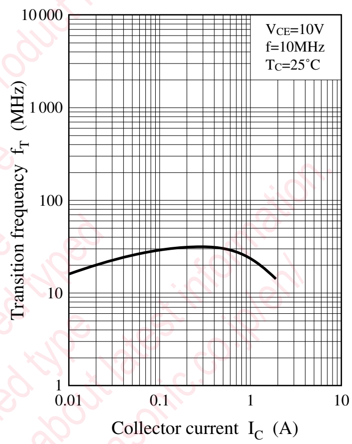
$V_{BE(sat)}$ — I_C



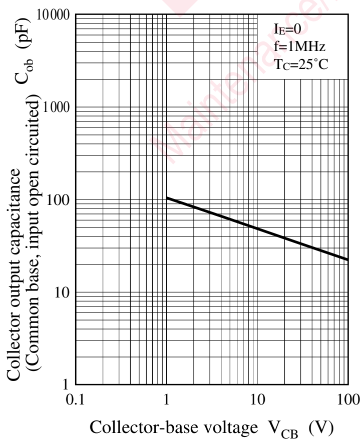
h_{FE} — I_C



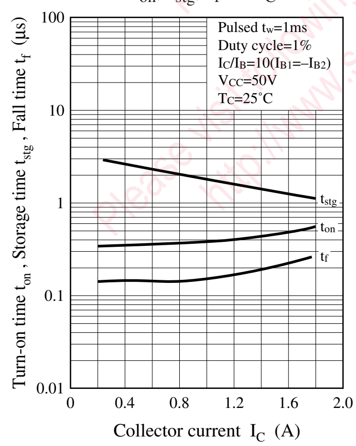
f_T — I_C



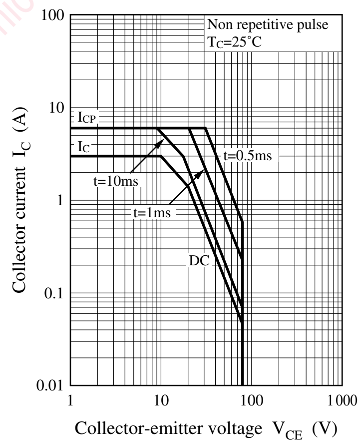
C_{ob} — V_{CB}



t_{on}, t_{stg}, t_f — I_C



Safe operation area



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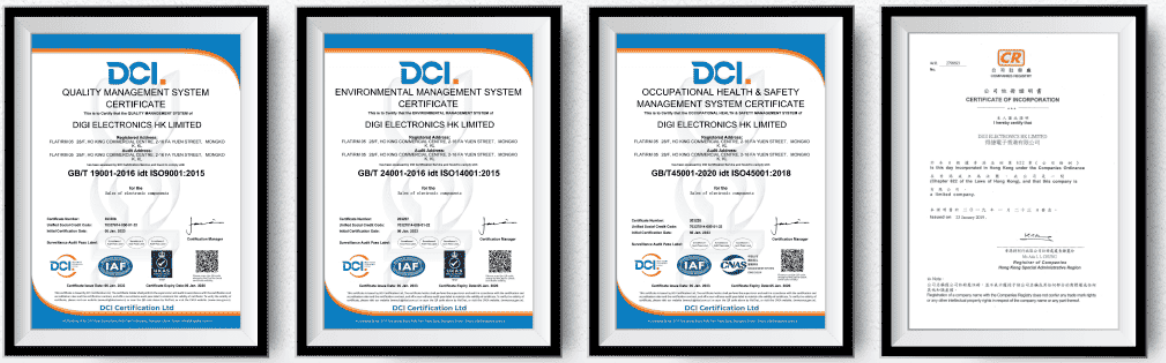

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